PDFN3×3A-8L N MOS

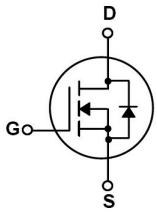
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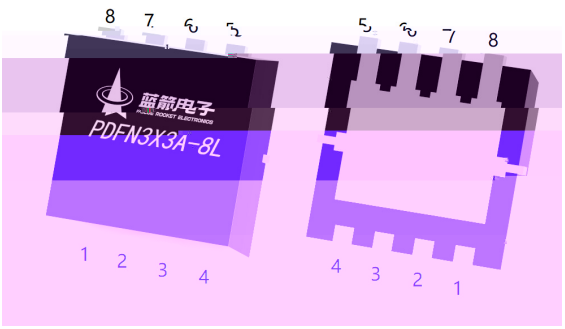
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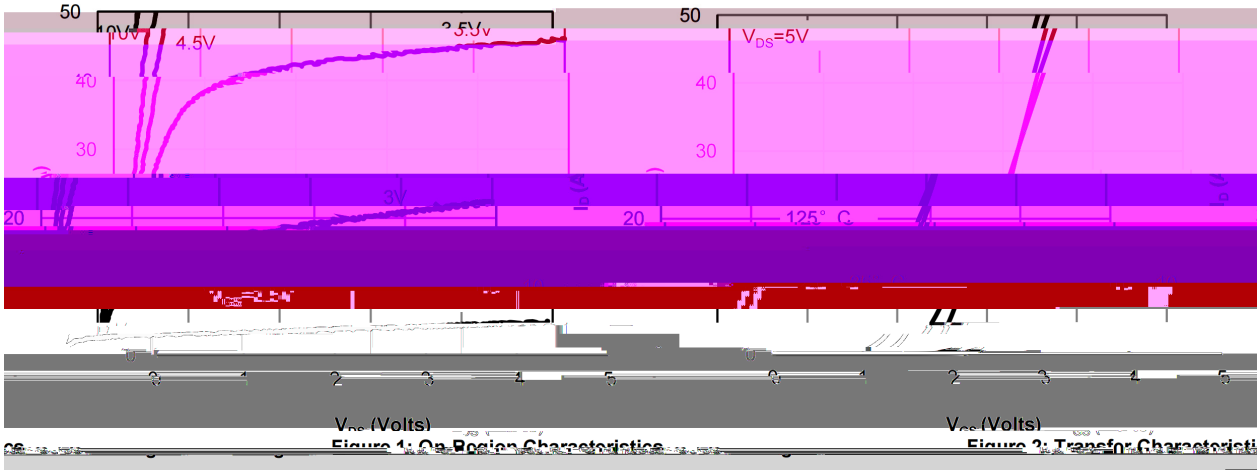
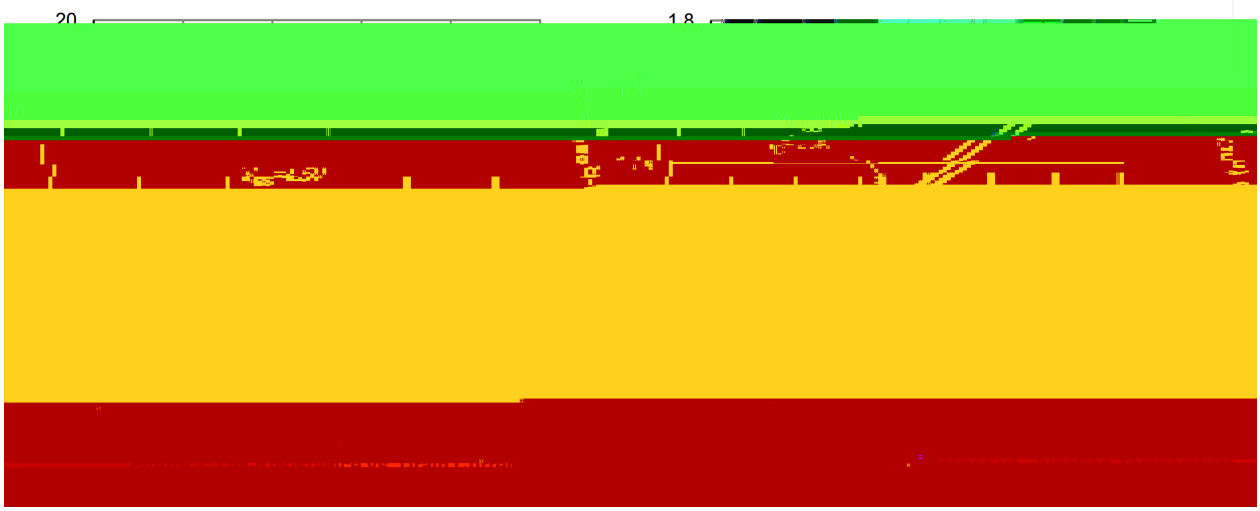
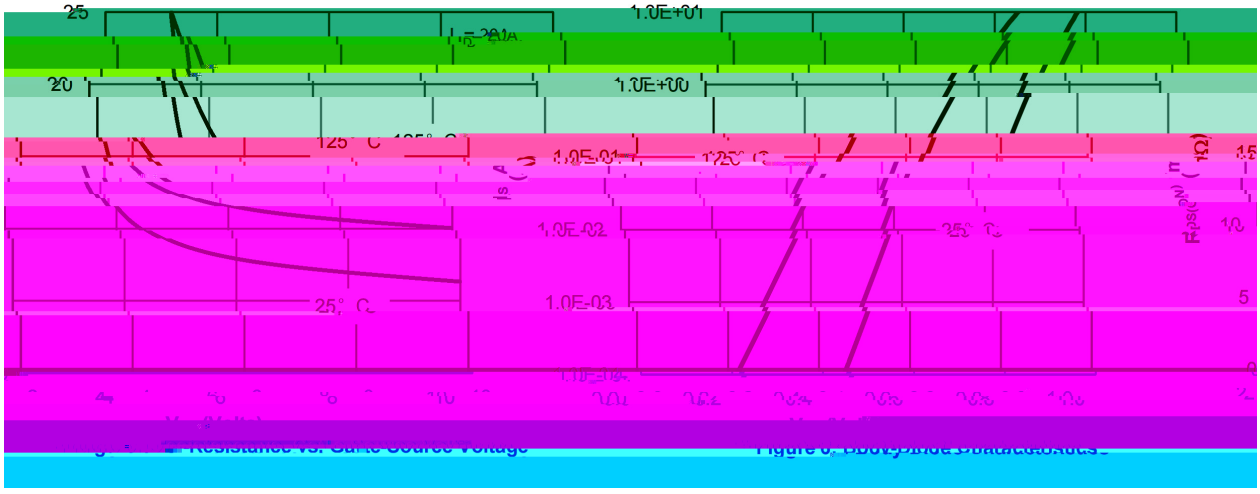


Figure 1: On-Region Characteristics

Figure 2: Transfer Characteristi

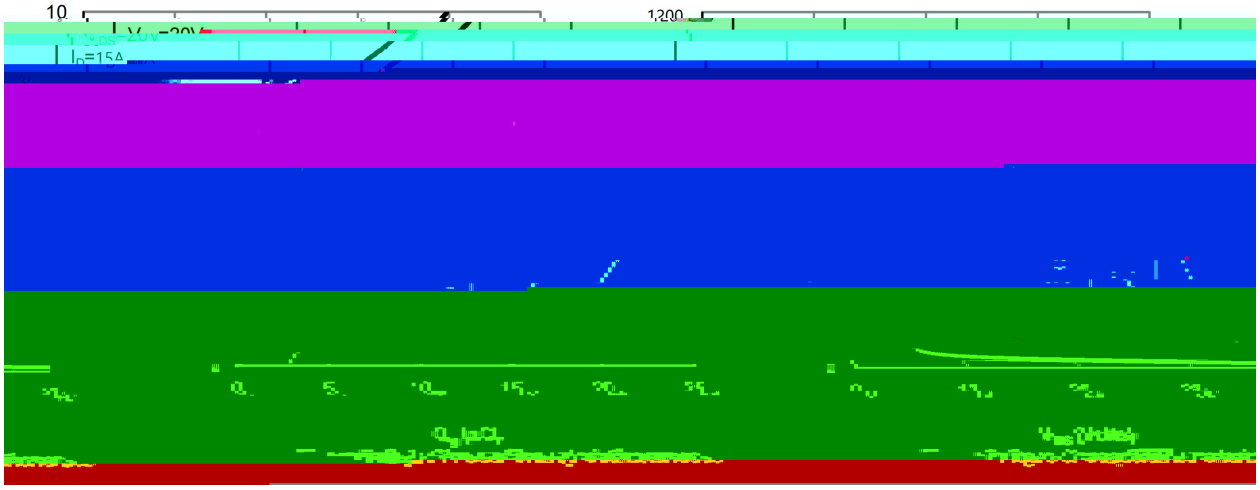




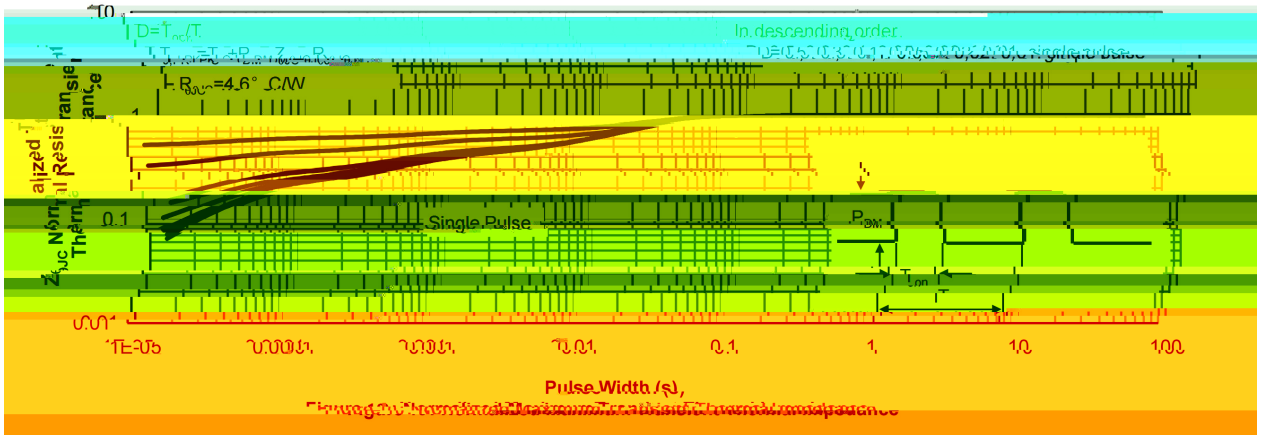
Resistance vs. Gate-Source Voltage

Figure 6: Body-Diode Characteristics

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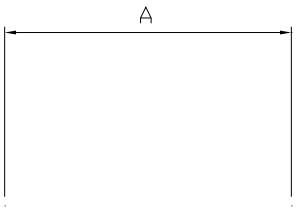




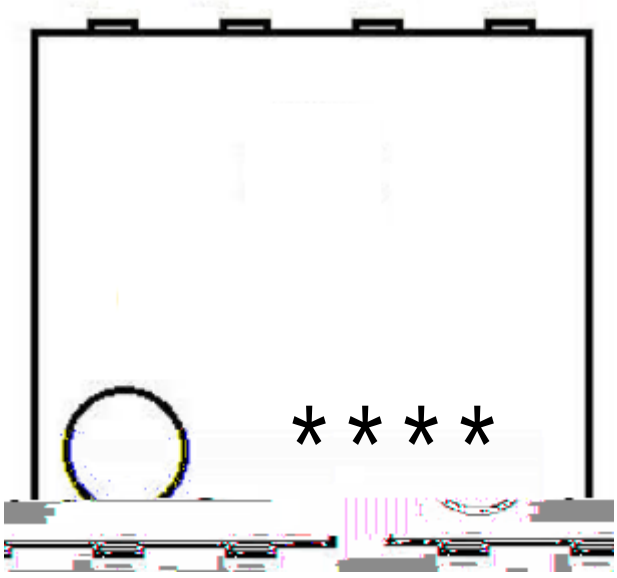

D=Ton/T
In descending order
RθJC=4.6°C/W
Single Pulse
Pulse Width (s)

PDFN3X3A-8L

Unit:mm



Rev.00



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